

50V/7A Switching Applications

Applications

· Relay drivers, high-speed inverters, converters, and other general high-current switching applications.

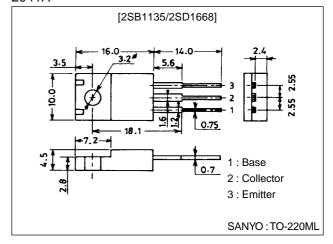
Features

- \cdot Low-saturation collector-to-emitter voltage : $V_{CE(sat)}\!\!=\!\!-0.4V$ max.
- · Wide ASO leading to high resistance to breakdown.
- · Micaless package facilitating mounting.

Package Dimensions

unit:mm

2041A



(): 2SB1135

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)60	V
Collector-to-Emitter Voltage	V _{CEO}		(-)50	V
Emitter-to-Base Voltage	V _{EBO}		(–)6	V
Collector Current	IC		(-)7	Α
Collector Current (Pulse)	I _{CP}		(–)12	Α
Collector Dissipation	PC		2	W
		Tc=25°C	30	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
Faiailletei	Symbol	Conditions		typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)40V, I _E =0			(–)0.1	mA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(–)0.1	mA
DC Current Gain	h _{FE} 1	V _{CE} =(-)2V, I _C =(-)1A	70*		280*	
	h _{FE} 2	V _{CE} =(-)2V, I _C =(-)5A	30			
Gain-Bandwidth Product	fT	V _{CE} =(-)5V, I _C =(-)1A		10		MHz
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)4A, I _B =(-)0.4A			(-)0.4	V

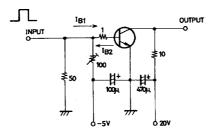
 $[\]ast$: The 2SB1135/2SD1668 are classified by 1A h_{FE} as follows :

	70	Q	140	100	R	200	140	S	280	
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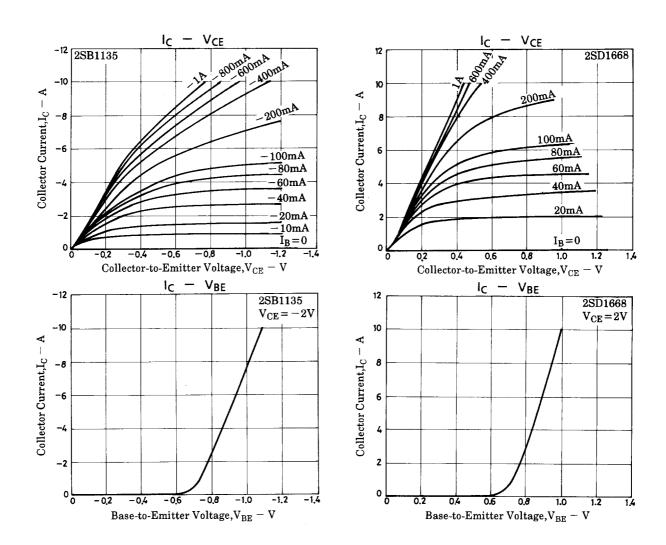
Parameter	Symbol	Conditions	Ratings			Unit
Farameter	Symbol	Conditions	min	typ	max	Offit
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)1mA, I _E =0	(–)60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(-)1mA, R _{BE} =∞	(–)50			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(-)1mA, I _C =0	(–)6			V
Rise Time	ton	See specified Test Circuti.		0.2		μs
Storage Time	t _{stg}	See specified Test Circuit.		(0.7)		μs
				0.9		μs
Fall Time	t _f	See specified Test Circuit.		(0.1)		μs
				0.3		μs

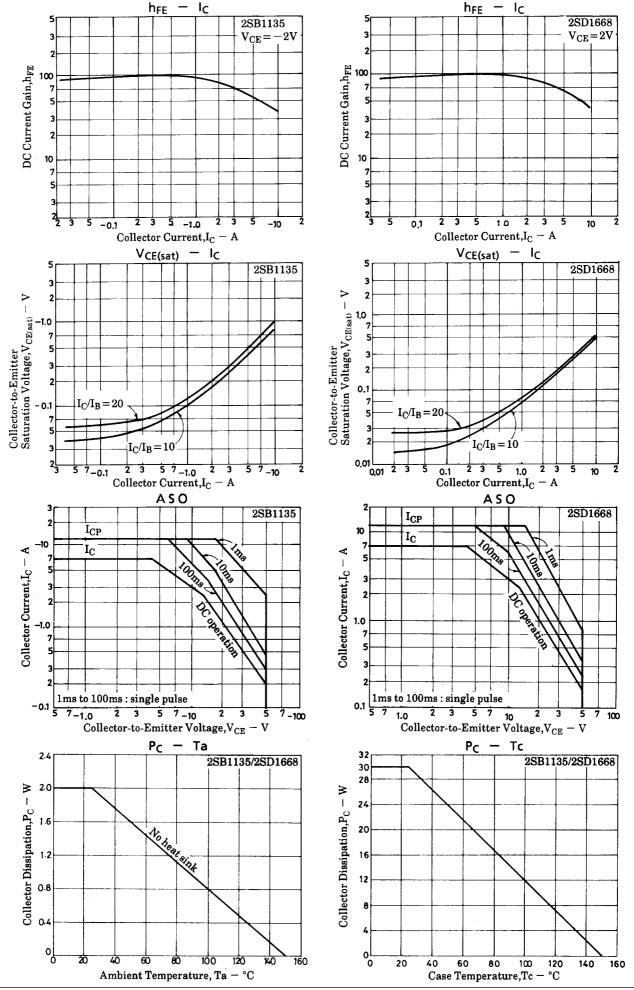
Switching Time Test Circuit



 $10I_{B1} = -10I_{B2} = I_{C} = 2A$

For PNP, the polarity is reversed. Unit (resistance : Ω , capacitance : F)





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